

ANYBODY picking up and dialing a telephone at this moment starts a chain of switching actions that links his phone through a unique voice pathway to any one of the 88 million telephones in the United States. A million people may pick up their phones at the same time with similar results. If a few hundred of these people are served by the same central office, their calls are handled side by side although the connections for each one may be directed by separate groups of control equipment.

From the customer's point of view, No. 1 ESS will handle ordinary telephone calls in the same way an electromechanical office handles them. They will seem to go through side by side, and the actions set in motion when a call is originated will continue in an apparently unbroken sequence until the connection is made. Actually, No. 1 ESS works on only one call at a time; its enormous operating speed makes it appear to handle all calls simultaneously. Furthermore, while in an electromechanical system each action in the switching sequence triggers the action that follows it, in No. 1 ESS the program is the trigger. It may direct the system to send dial tone to a telephone originating a call, then make a connection to the switching network for a second call, go on to take down connections for a third call, and only then return to the first call to receive dialed digits. Thus any step in processing a single call is isolated, so to speak, from any other.

The actual circuit actions that accomplish each step in the processing take place in central control. Every 5.5 microseconds one of the 100,000 instruction words that make up the stored program directs central control in some basic action of call processing or automatic maintenance. The flow of actions follows a precise schedule because central control can execute only one instruction at a time and each step may have a different duration. For example, during dialing lines are scanned periodically to detect the dialed digits.

This diagram shows all the programs that participate in advancing a call from its origination to the talking connection. The order in which the programs take control from the executive program can be followed by reading down the left side of the diagram. The large blocks represent the functional programs, the smaller ones are the various subroutines which gather specialized information as it is needed at any step in the progress of the call. This information is passed between the various programs by means of the call store hoppers, the buffers, and the registers in the memory section, in the center of the diagram.

Scanning must be done fast enough so that no digit pulses are missed. On the other hand, the switching network operates more slowly. Hence, instructions to make connections in the network are issued at a correspondingly slower rate. These varying time cycles are reflected in the overall organization of the program.

The stored program contains five functional groups of programs each controlling a particular stage in call processing. First, *input programs* gather information such as the states of all lines, trunks, and service circuits. *Operational programs* examine this information and decide what, if any, output actions are required in response to it. The operational programs also call on *subroutines* to fetch data that the *output programs* will use. Finally, the output programs make and release connections in the switching network and operate relays in the trunk and service circuits. During the time that central control is involved with the specialized actions outlined by a functional program, that program actually controls the system. Each program assumes and relinquishes control on a strict schedule that is governed by the fifth functional group, the *executive control program*, which decides when each of the first four are to be called into operation.

To smooth the flow of the whole process, the call store memory acts as a clearing house of information between the functional groups. The call store is divided into many sections, each with a number of words, or memory slots, called registers, hoppers, and buffers, in which information is deposited and withdrawn as it is needed. One or more registers is associated with each telephone call being processed. Input programs fill the hoppers with input information that is operated on by the operational programs. These, together with the subroutines, stock buffers with output information for the output programs. Thus the processing of any call entails a constant interplay between the program store and the call store.

A familiar starting point for describing how a switching system handles a call is the customer's act of lifting his telephone handset from its cradle. In No. 1 ESS, as in all other systems, that act signals the origination of a call. But from that point on, No. 1 ESS is different from all other systems. The state (off-hook or on-hook) of a customer's line is reflected in one of the two possible states of the ferrod sensor. When the customer lifts his handset, the ferrod changes its state. (See *From Morris to Succasunna* in this issue.)

Every 200 milliseconds, the executive control program schedules an input program, called the line scanning program, that in turn directs cen-

tral control to scan all ferrods. The object is to discover which ferrods have changed state since the last scan, 200 milliseconds before. Each time it discovers a change, the program temporarily stops the scanning action and writes the equipment number of the originating line in a hopper reserved for service requests. The system always completes the immediate action on one line before it goes to the next. Thus, though it will take the same action on all originating lines, it works on only one at a time. When all the ferrods have been scanned, the scanning program returns control to the executive program.

At this point, any line that has gone off-hook since the last scan is identified in the service request hopper. The executive program now decides on the next action. To take further action on the service requests stored in the hopper, it must schedule an operational program. But it may decide instead to give control to an output program; for example, to operate the line switching network. A single network control device can be used only once in about every 20 milliseconds. But to preclude any possible "traffic jam," the program directs any controller to operate only once every 25 milliseconds and in the interval directs actions elsewhere in the system. Meanwhile, the service requests wait for an operational program. Thus, the initial step in the call may have no direct connection in time with the next step. This may also be the case with any other sequential steps.

The drawing on page 216 traces all the program steps that occur as a call progresses from its initiation to a talking connection. As the call moves through the office, control is handed back and forth between the executive control program and the functional programs. A functional program may complete a call processing step on one line, and then return control to the executive program. The latter may direct the functional program to proceed immediately to the next waiting line, or it may schedule another program. Any program is interrupted when a network operation or a digit scanning program is due.

Frequently, the system needs special information concerning its next step in a call. For example, conventional dial telephones and TOUCH-TONE® dial telephones require different types of digit receiver circuits. When a customer initiates a call, however, the system first detects only a change of state in the line. It does not know which type of telephone is involved, and therefore it does not know which type of digit receiver circuit to connect. The dialing connection program, which is in control at the time, gives the calling line's equipment number to a translation subroutine

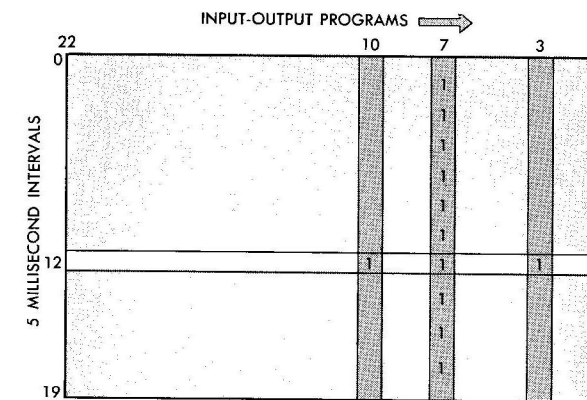
which refers it to a translation "list" in the program store. This list contains information on the kind of equipment associated with the line. The subroutine passes the information back to the dialing connection program which then knows which type of digit receiver the line requires.

Every regular and specialized action in the process of making a connection between two telephones is thoroughly covered by one or more functional programs. Like a conductor who cues in each section of his orchestra at the proper time, the executive control program schedules the functional programs. The sections of the No. 1 ESS orchestra all play different themes that blend contrapuntally. And the final phrase in any call is a variation on the opening: When the conversation ends and both parties hang up, a scanning program detects a change of state in the ferrods and the system knows that the connection can be released.

The efficiency of this intricate plan turns on the precise scheduling of the various programs, particularly the input programs. Unlike output signals, which are controlled by the program, input signals originate at customers' telephones or in distant offices. If any are missed or received inaccurately, calls will go astray. Besides, many input signals, such as dialed-digit pulses, exist only momentarily, and may vanish unless the program that detects them is scheduled unerringly and unvaryingly to the millisecond. Input programs, therefore, take precedence over any other job in the system. Every 5 milliseconds the program in progress is stopped and an input program—digit scanning, trunk scanning, junctor scanning, or whatever—takes control.

If the programs were to time their own control periods, making the transition from a call processing routine to an input detecting routine every 5 milliseconds, they would all have to be written to account for both the random occurrence of inputs and the rigid timing requirements of such peripheral system equipment as the network frames and the multifrequency transmitters. However, because the executive control program determines which functional programs are to have control at any given time, the programs themselves need not be concerned with timing.

Two "timetables," each a matrix of binary digits in the call store, provide the executive control program with the specific timing indications it requires. One, the 20×5 millisecond timetable (see the drawing on page 219), is a matrix of 20 rows and 23 columns; the other, the 24×5 millisecond timetable, has 24 rows and 23 columns. In both cases, each column is assigned to one input program and at each row a binary 1 or a binary 0



The 20×5 millisecond timetable contained in the call store memory. Each vertical column is assigned to a specific program which is executed whenever a binary 1 appears at the intersection of the column and a horizontal row. Thus, the program in column 7 is executed every other round, or every 10 milliseconds. At the 12th round the programs in rows 10, 7, and 3 are executed.

is written in the column. The rows are read in turn, one every 5 milliseconds, and whenever a binary 1 appears, the program for that column is executed. If a binary 0 appears in the column, the program is skipped that round. Thus, the program that controls digit scanning, which is executed every 10 milliseconds, has a binary 1 in every other row. Reading is continuous; when all rows are read, the cycle begins again.

An obvious limitation to these timetables is that they cannot be used for sequences that do not repeat themselves either every 100 milliseconds or every 120 milliseconds. Therefore, other timing sequences required by the system are generated by a "revolving counter." This technique is effective for any sequence that repeats itself regularly. A counter consists of a number of bits in a call store word. At regular intervals, the leftmost bit is rotated to the opposite end of the word. Whenever that leftmost bit is a binary 1, a program is executed. The signal to rotate the leftmost bit is taken from the 24×5 millisecond timetable.

For example, a dial pulse transmission program is performed reiteratively at 45 milliseconds, 60 milliseconds, 45 milliseconds, 60 milliseconds, etc. This sequence is triggered by the 7-bit revolving counter 1000100. At every third interval of the 24×5 millisecond timetable, that is, every 15 milliseconds, its output is applied to the counter, causing the leftmost bit to rotate. A complete rotation of the counter takes 105 milliseconds and a

binary 1 appears at the leftmost position every 45 and every 60 milliseconds.

The handling of the input programs underlines an idea that is indispensable to the stored program method of processing telephone calls: Certain programs can be delayed while others are executed. Simple as this idea sounds, the No. 1 ESS philosophy of time sharing one control unit among all the lines in an office would be unworkable if all programs had the same priority. Although few programs besides the input and output programs must be executed in real time, service requests must be dispatched with the least possible delay. Programs such as routine maintenance, on the other hand, can be deferred to slack traffic hours. All programs, therefore, are woven into a hierarchical order based on their relative importance.

A basic order of priority assignments is given to "task dispenser" programs, specialized programs associated with specialized buffers in the call store. The task dispensers are active links between the executive program and the "task" programs that carry out the processing routines on the data in the buffers. Because the buffers accumulate information of varying degrees of importance, they must be unloaded according to a strict priority scheme. Therefore, the task dispenser programs are grouped in six classes. The highest priority is called "interject;" the other five are classes A, B, C, D, and E. Class A dispensers, the highest priority of the five, cannot be delayed more than 200 milliseconds, while class E dispensers, the lowest priority, can be deferred as much as 2 seconds. A continuously repeating sequence governs the execution of the dispenser programs. Each priority class in the sequence is run twice as often as the class directly below it. The actual sequence—

ABACABADABACABABACABADABACABAE—contains class A 15 times, class B 8 times, class C 4 times, class D twice, and class E only once.

On links between the executive and the operational programs, the actual job of the task dispenser programs is to examine the data stored in the buffers and determine the operational programs that must be called in to operate on it. Specialized task programs are then called upon to do whatever the data calls for—direct a scanning program on specific lines, or start a network operation, for example. When it finishes its work, the task program returns control to the task dispenser which immediately checks for waiting interject work. If there is none, the task dispenser again examines its associated buffer, and the cycle continues. When all task dispensers in one priority class are completed and their buffers are cleared,

STATE WORD
QUEUE WORD
LINK WORD
SCAN WORD
PATH MEMORY
DATA

Simplified layout of a call store register. The type of information stored in some words or parts of words varies with the type of call, and can change as the call progresses. The scan word is not always used. Its function is to link a call store register to a scanning register when the program orders that some point in the system be scanned.

the sequence moves to the next class.

Interject programs may be “interjected” at any point in the sequence. One example, is the 1000 millisecond timing program which keeps a record of the time and the date and maintains a 10 × 100 millisecond timetable. This program is run every 100 milliseconds on an interject request from the 20 × 5 millisecond timetable. A program schedule in the 10 × 100 millisecond timetable may be executed when it becomes due (“times out”), or it may be rescheduled at a lower priority by writing a binary 1 (called setting a flag) in certain control registers. These flags direct the executive control program to execute specified task dispensers or to consult timetables that have periods larger than one second. This method of cascading timetables allows the executive control program to schedule programs that repeat as often as every 100 milliseconds or as seldom as once a week.

All the individual threads of the program that we have discussed are woven together in the call store memory. Every call, in its progress through the office, is assigned to a call store register which consists of memory slots for the temporary storage of input and control data. (See the drawing on this page.) Some stages of a call require more memory space than others. During digit scanning up to ten digits may be stored, for example. Thus, there are different sized registers for different stages of a call. However, the program subroutines handle all registers in the same fashion because the first three words of all registers, called the state word, the queue word, and the link word, respectively, are alike.

The state word identifies the register by its function—originating, outpulsing, disconnecting, etc.—and its particular state. The latter is shown

by an index called the program tag. When the register receives an input from a task dispenser, the state word selects a group of four task programs appropriate to the particular stage of processing. The exact program is selected from the four by reference to the type of task dispenser that delivered the input entry. Thus, instead of following a complex branching process to narrow down the choice of a program by many either-or decisions, the register simply looks for the proper program in a table.

The queue word links the register to a waiting queue when needed peripheral equipment, such as a ringing trunk, is tied up on another call. In this case, when the trunk becomes available, the queue administration program assigns the equipment to the register on the queue and transfers control to the task program selected by the state word.

The link word links a number of registers together if more than one is required for a call. This may occur, for example, on a call that is transferred to a remote station outside the central office. At one stage in this procedure an originating register, a temporary transfer register, and an automatic message accounting register are linked together. Any number of registers can be linked together by placing the address of the state word of the second register in the link word of the first register, the address of the state word of the third register in the link word of the second register, etc., finally closing the chain by placing the address of the state word of the first register in the link word of the last. Buffer entries to any one register in the chain can be passed to all of them. When a register receives a report of a buffer entry, its program tag is changed so that future entries will select the task program appropriate to the then current state of the call.

The No. 1 ESS program is obviously the operating intelligence of the system. Its structure is determined mainly by the very large call handling capacity demanded of the system, and the fact that it must respond to service requests in real time (as they occur). Although specific data such as equipment quantities and translations, which change from office to office, are not written into the program, they are easily added to the memory system in any office. If the details of a special service or feature is changed, or a new one is added, the program is easily modified to incorporate it. From this stems the considerable, but quite realizable, claim that No. 1 ESS can handle telephone features and services that have not yet been foreseen.



The program store modules of the Succasunna office of ESS. These 16 modules hold more than 5 million bits of information.

The control unit of No. 1 ESS operates in the rapidly changing environment of a telephone central office. Its main task is to continuously monitor and control that environment so that all customers can be served efficiently and accurately.

The Control Unit

A. H. Doblmaier

THE CONTROL UNIT of No. 1 ESS, consisting of the stores and central control, is a binary digital machine that performs highly complex logic operations which interpret the instructions of the stored program for the system. All the telephone switching logic is contained in the stored program, but the processing logic resides in the 13,000 logic circuits of central control with their almost 60,000 semiconductors. To change system features requires changing the program, but as long as programs are written in a common machine language central control logic circuits will execute any orders they receive. Because this processing is performed at the high speeds of electronic devices, the control unit of No. 1 ESS represents the ultimate degree of common control—one control directs the entire system.

Central control, the active part of the control unit, decodes and executes the organized set of binary encoded program instructions at a nominal rate of one every 5.5 microseconds. Clock pulses originating in a 2-megacycle crystal oscillator establish the execution rate. The binary characteristic is basic to the design of the control unit. Logic circuit transistors, for example, are two state devices, switching between on and off in a few nanoseconds.

There are three major classes of instructions to central control. The first consists of orders for central control to *sense* the state of the environment. For example, an order may require examining the ferrod line scanner associated with customers' lines in order to detect requests for service. Central control detects any change of state in the line as a binary zero or binary one signifying off-hook or on-hook. In general, scanning is used to detect inputs to the system.

A second class of instructions processes the input data. Processing steps may include manipulating the data within central control, storing the results in the call store and recalling them when they are needed, and obtaining auxiliary data from the program store. But the processing of data may not be a perfectly straightforward progression from one step to the next. Central control's real power lies in its ability to decide, at any stage in the sequence, whether to continue through the program in an uninterrupted line or to jump to another area. Central control makes these conditional transfers on encountering certain conditions. It may, for example, look at the contents of a register and, according to what it finds, either transfer or continue the program.

The third class of instructions generates out-

puts from central control for operating relays in a trunk circuit, closing a network path, etc. As a rule, a single instruction governs a single operation. The complete set of instructions, however, is general enough so that individual instructions can be combined in various ways to implement any combination of office features.

In processing instructions, central control's first step is requesting information from the stores. It may retrieve service requests from the call store and ask for the processing instructions stored at a particular "address" in the program store. In return the program store sends central control a two-part instruction stored at that address. The first part of the instruction tells central control what to do with the information being processed. The second part, the address, tells where to do it.

Central control carries out the actions through various registers and flip-flop circuits, most of which are functionally designated. Program store addresses are generated in a program store address register and the instructions are received by an order word register. Call store addresses are generated in an index adder and data from the call store is received by a data buffer register. An instruction decoder is attached to the order word register. The decoded output of the order word register, combined with an appropriate clock pulse, controls the gating of information through the registers of central control. (The diagram on page 224 shows the organization of central control.)

There are eight general purpose flip-flop registers within central control connected together by two common buses. One or more of these

(designated B, F, J, K, X, Y, Z, and L registers) usually is involved with processing an instruction. Designed to accommodate the basic word length of central control, each register is 23 bits long and the interconnecting buses each comprise 23 parallel information paths. A call store word is actually 24 bits, so the data buffer register is 24 bits long. The 24th is a parity check bit which drops out in the data buffer register.

A program sequence of instructions to central control might proceed as follows:

One. Take a memory address from an index register and read the word containing the first dialed digit of a call. Mask out all bits in the word except the four used for the first digit, and store the word in an accumulator register. (Masking, done in a mask and complement circuit, consists of changing all bits in a word, except the significant ones, to zero.)

Two. Compare the word just placed in the register with the value 10 (the number of pulses counted when a customer dials zero).

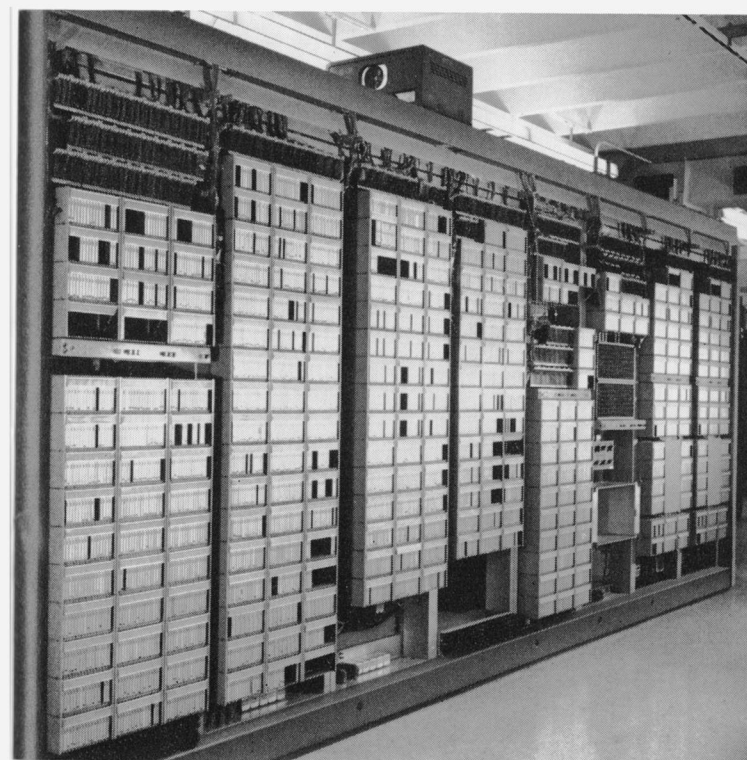
Three. If the two compared quantities are equal, transfer to the program at an address specified in the instruction. If the quantities are not equal continue with the present program sequence.

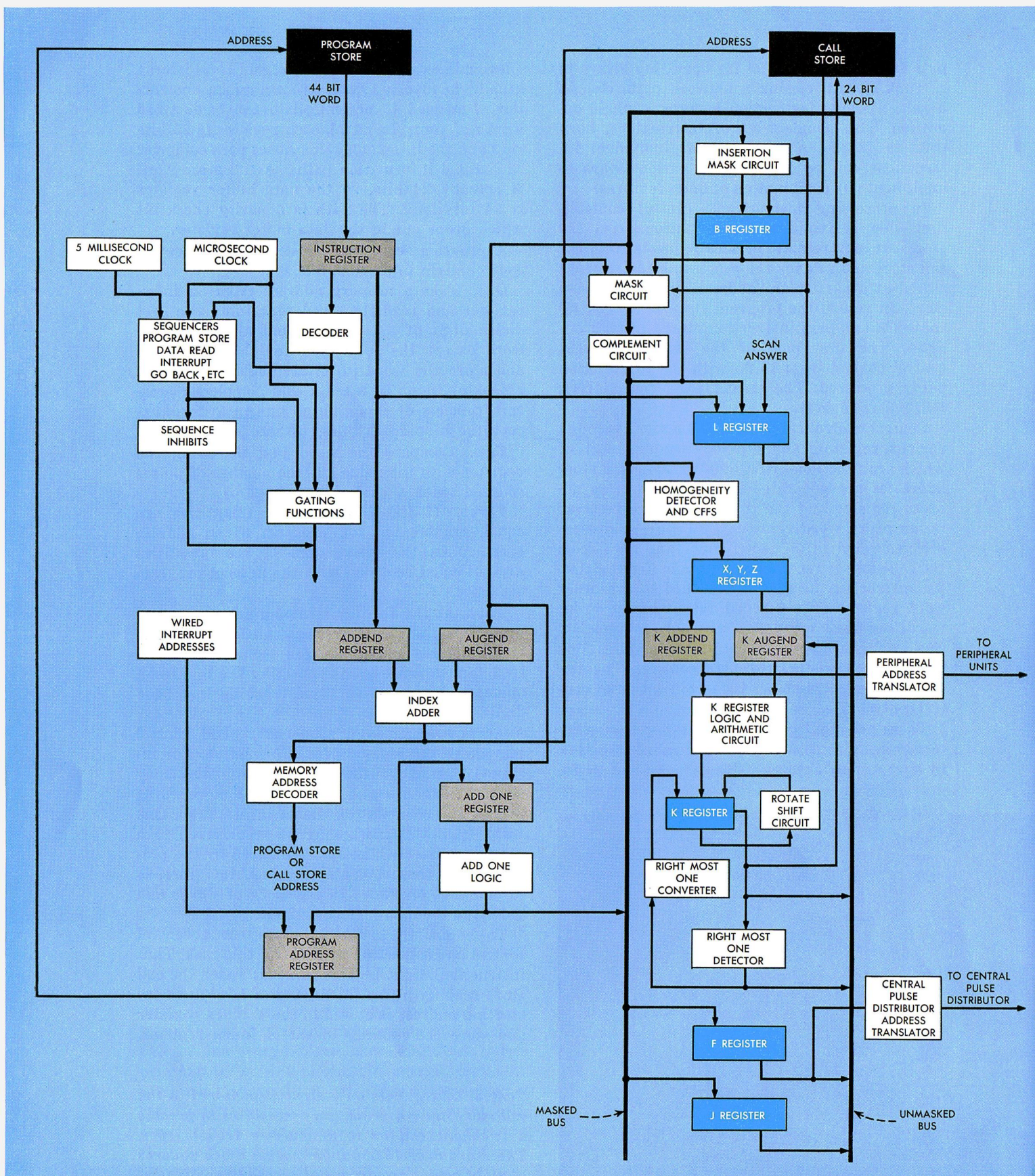
Thus, at the third instruction central control decides if the customer has dialed zero (i.e. if the compared quantities are equal.) If so, it transfers to a program connecting the line to an operator. If not, it continues reading up dialed digits.

At any stage in a sequence central control may go to the registers for information. For instance, one of the flip-flop index registers may contain the address of a block of call store words needed in accumulating dialed information. One word from this block may be transferred to a second register where it can be used by the program. The task of central control, therefore, is to find that one word in the block of words and gate it to the appropriate register.

To begin, the program store sends central control an instruction to perform this task. That instruction might be paraphrased: Fetch the call store reading in the third word of a block whose starting address is stored in the Y index register and store the reading in the X index register.

Central control acts on instructions stored in the call store and program store memories to process a telephone call or to diagnose a trouble spot. There are over 13,000 logic packs. Black squares at right center are groups of ferrod line scanners.





The actual instruction has three parts: first, the operation (fetch data from the memory and store it in the X register); second, a constant that identifies the pertinent word in the block; third, the address of the Y index register. All program instructions are written mnemonically. Memory to X register, for example, is written MX. If the constant in the second part of the instruction is, say, 3, then the instruction is written MX 3, Y.

To find the pertinent word in the block of words, central control sends two inputs to the index adder. One input is the constant of the instruction. The other is a variable representing the contents of the specified index register. The index adder adds the two and the output of the adder is the address of the desired word.

In processing data, central control manipulates arithmetic quantities and logic quantities, both of which are couched in the binary language of digital machines. Arithmetic numbers contain 23 bits, designated 0 to 22. The bit at the right, is called the least significant bit; the one at the left, the most significant bit. Bit 22, the sign bit, distinguishes between positive and negative numbers. For a positive number the sign bit is 0. Negative numbers are expressed as the "ones" complement of their positive equivalent, and their sign bit is 1. For example, +1 is 000...001; -1 is 111...110.

An arithmetic circuit in central control adds, subtracts, compares, shifts, and rotates binary numbers. (Neither call processing, nor any other system function requires division or multiplication.) In addition to these arithmetic operations, the arithmetic circuit performs the logical operations AND, OR, and EXCLUSIVE-OR. (The role of the logic functions in line scanning is shown on page 200.)

In many cases, particular bits of information are not located in the most convenient bit positions in a word. This may occur, for example, if several small data words are packed together into adjacent bits of a large memory word. Masking can be used to isolate a word within a larger word, but it does not affect the relative bit position. To move these bits into a more convenient position, the word can be transferred to an ac-

cumulator register in the arithmetic circuit which shifts or rotates the bits to other positions in the word.

In rotation, bits are passed through one end of the accumulator register and reinserted at the other end so that no information is lost. One bit, or a few, or all the bits in a word can be rotated as necessary, and it can be done from left to right or in the opposite direction. (Actually, the word is rotated as a unit by any specified number of places.) In shifting, the bits are forced out of either end of the register, but the vacant positions are then filled with zeros.

Another useful function in central control data processing is the rightmost one function. It consists of detecting and identifying a binary one in the midst of a number of binary zeros in a word. The one may signify, for example, an idle trunk. If central control is seeking a trunk over which to complete a call, the one indicates an idle trunk in the group, the zeros, busy trunks. The word storing the states of the group of trunks is gated to the accumulator. A rightmost one detect circuit then gates the position of the rightmost one to the F register through the buses. (F stands for "first one".)

Sometimes, when a task is performed on a number of successive memory locations, it is convenient to set an index register to the binary value of the first memory address in the sequence, then to add 1 to the register to each succeeding word. This function, called "incrementing" is particularly useful in "looping" programs. For example, the instruction $\text{MX } 3, Y$ gates the contents of the memory at the address $Y + 3$ into the X register. But $\text{MX } 3, Y\text{A}$ gates the contents of the memory at $Y + 3$ into the X register and increments Y by 1.

The index register may also be modified by changing it to an indexed quantity. In the instruction MX 3, YW, the W is the indexed quantity. This instruction changes the index register, Y to the value of W which is the original value of Y, plus 3.

A final index register modification sets up the memory address to a specified quantity. MX 300, SY reads the memory at address 300 into the X register and places the quantity 300 into the Y register. (In the program mnemonics SY means set up Y.)

Two general approaches are common in the design of machines like central control—asynchronous and synchronous. An asynchronous machine works on the basis of a continuous flow of actions, each one triggering the next. A signal verifies that one action is completed before the



Continuous pulse testing is performed on all twistor wire for the permanent magnet twistor memory to ensure that the signal levels are uniform for binary one and binary zero readouts. L. L. Vanskike performs the test on wire to be fabricated into the device.

All the telephone switching logic and any other data vital to the completion of telephone calls are stored as binary bits in the memory cells of two new memory devices in No. 1 ESS—the ferrite sheet and the permanent magnet twistor.

Memory Devices

R. H. Meinken and L. W. Stammerjohn

THE BASIC OPERATION of the memory devices in No. 1 ESS consists of storing a binary digit or "bit" in a specific location, called a memory cell, and recalling it on command. When memory cells are combined in large arrays, millions of bits can be stored in a single memory. Some bits are recalled after only a few millionths of a second. Others may be stored for years and recalled repeatedly as often as they are needed. To understand the operation of large memories, we can start with the behavior of a single cell.

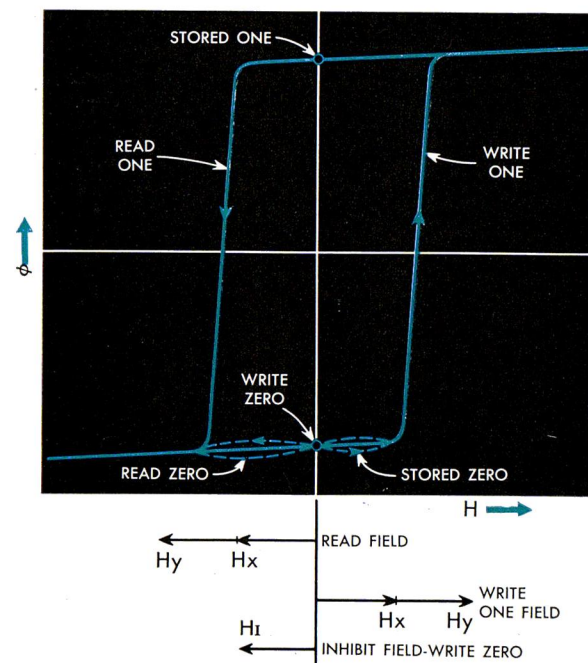
A material or a device that has at least two stable states has memory. An ordinary light switch, for example, has two stable states, on and off, and by its position "remembers" a manual command. Electromagnetic switches or relays remember an electrical command, and they have functioned as memory devices in the telephone plant for many years. These devices, however, cannot operate at the high speeds demanded by modern electronic systems.

Memory elements prepared from specially developed magnetic materials have a number of properties that make them eminently suitable for high-speed systems. The fundamental prop-

erty, their two stable states, is expressed as opposite directions of magnetization. But more significantly, these elements can be made to switch very rapidly from one direction of magnetization to the other. Furthermore, the coercive force of the material provides a threshold of operation that prevents small amounts of extraneous energy from changing the direction accidentally.

In the last few years, magnetic core memories have been used widely in digital systems. Both the permanent magnet twistor memory and the ferrite sheet memory of No. 1 ESS are related to these. In the simplest form of core memory, thousands of cores are assembled in a coordinate frame of wires. Two wires intersect orthogonally (in the X and Y directions, that is) at each core. A core can be magnetized in either a clockwise or counterclockwise direction; one way represents a binary zero, the other a binary one. A general description of the operation of core memories is a good foundation on which to build a comprehension of the twistor and ferrite sheet memories of No. 1 ESS.

To store or "write" a digit in a core memory, we control, or select, the direction of a core's



Hysteresis loop of the ferrite material which composes the memory cell of the call store memory showing X, Y, and inhibit fields and one and zero flux states. The inhibit (write zero) field, added to the write one field, prevents the memory cell from switching and leaves the bit in the zero state.

magnetization by passing currents through the wires. Half the value of the current required to switch the core is applied to an X-column wire, the other half to a Y-row wire. Since the value of the current in each wire is less than the threshold of operation, the magnetization of a core is not changed if only one of the wires passing through it carries current. Only the core at the intersection of the two wires that receives their coincident currents is affected. After it has been set in either direction, a core remains magnetized without any applied current.

To recall or "read" the digit stored in a core, coincident currents are used again. If a core at the point of coincidence is already magnetized in the direction that would be induced by the current, it does not change. But if it is in the opposite state, it switches, and the reversal of the magnetic flux induces a voltage pulse in a "sensing" wire. Reading the memory, then, consists of sensing the pattern of voltages and no-voltages.

In this description, we have reduced the reading operation to its simplest level, the single bit. A memory that could read out only one bit at a time would be thoroughly inefficient for a high-

speed system, however. Bits are actually strung together in parallel combinations, called words, and read out of the memory in aggregate. The structure and length of the binary words in any memory is determined by the requirements of the system. In core memories it is possible to form words of almost any bit length by connecting the cores in proper wiring patterns.

Up to this point we have been dealing with characteristics that are true not only of No. 1 ESS memories, but of the memories in many kinds of digital systems. Beyond these general ideas, however, the No. 1 ESS memories differ in significant ways from other memories and from each other. Electrically and mechanically, each is designed to suit its unique functions. These functions, described by the names temporary memory or call store for the ferrite sheet and semipermanent memory or program store for the twistor, have been discussed elsewhere in this issue. (See *Features and Services*.) Now let us take a detailed look at the most important principles in the design of first the ferrite sheet and then the twistor. After that we will consider some of the problems involved in achieving reliability and economy for these devices.

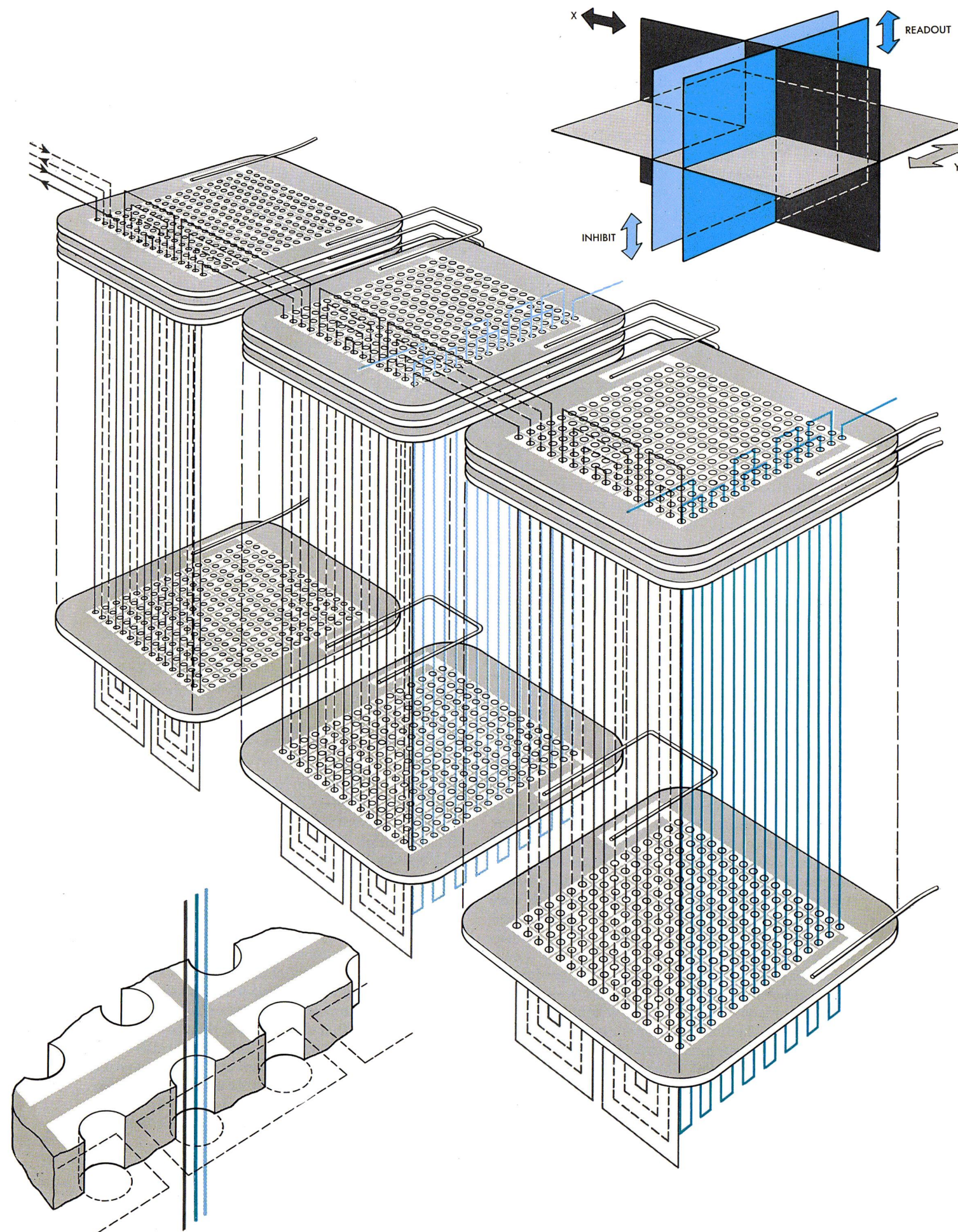
The Ferrite Sheet Memory

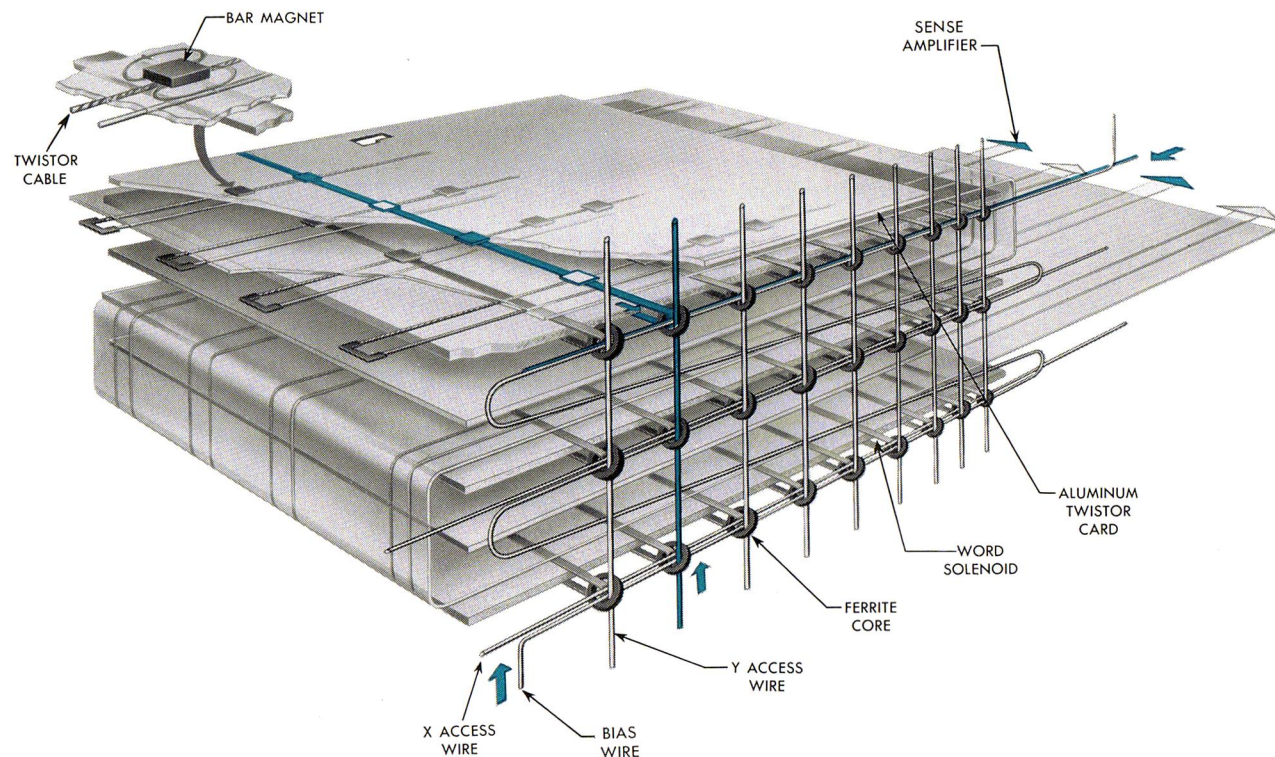
The mechanical construction of the ferrite sheet memory is modular. Four modules compose one call store. A module contains 192 separate ferrite sheets arranged in three adjacent stacks of 64 sheets. The storage capacity of each call store in a No. 1 ESS office is 8192 words of 24 bits each.

A single ferrite sheet contains 256 holes on a 16 by 16 grid. The material surrounding each hole is a memory cell similar to a single core in the core memory. This material is a bistable ferrite (i.e. it has a "square-loop" magnetization or hysteresis curve) that is uniform in composition. It was specially developed for these characteristics to permit coincident-current operation.

The ferrite sheet memory is similar to the core arrangement that has been described. Four conductors, called X, Y, sense, and inhibit windings, carry the currents used in reading information

The sense, inhibit, and X wires of the ferrite sheet are continuously threaded through all 64 sheets in each stack of the module. The Y wires are formed by interconnecting plated conductors on three sheets on each level. A single word is read out by selecting one of 64 Y inputs and one of 32 X inputs. The selected word is contained as one bit in each of 24 memory cells coupled to the two inputs.





Reading a word out of the twistor memory involves access windings, biased ferrite core switches, word solenoids, twistor elements, and sense amplifiers. Magnetized cells (binary zero) are the blue bar magnets in this drawing, unmagnetized ones (binary one) are white. The fields in two intersecting access windings select a core (the one at the intersection of the blue X-access and

Y-access wires) and induce a current in its copper solenoid. Twistor elements under unmagnetized cells switch and generate a pulse of a few millivolts which the white sense amplifier detects. Twistor elements under magnetized cells are biased into saturation and cannot switch. This generates a less than one millivolt pulse which the blue sense amplifier detects and interprets as a binary zero.

out of the memory or writing it in. As in the core memory, coincident currents switch the memory cell at the juncture of the X and Y conductors. Pulses induced in the sense windings represent bits read out of the core. The inhibit winding is functionally named. To prevent a cell from switching during writing, a pulse is sent over this wire simultaneously with, but in the opposite direction from, the pulses over the X and Y conductors.

Reading and writing operations are performed in the following manner. The memory element is selected, or addressed, by a coincidence of X and Y currents. The current pulses are bipolar; that is, a negative current pulse is always followed by a positive current pulse. The first, or negative part of the bipolar pulse, reads the memory cell. The positive part of the bipolar pulse writes into the cell. Current pulses are applied to the in-

hibit winding only during the writing operation.

In reading, the negative field created by the negative current pulses reverses the direction of magnetization in a cell in which a one is stored. The change in the magnetic flux induces a voltage pulse in the sense winding. The amplitude of this pulse is read as a binary one. A cell in which a zero is stored, however, is changed in its degree of magnetization only slightly by the negative field. This small reversible change induces a much smaller voltage in the sense wire. This pulse is read as a binary zero. After a cell is read and the negative field is removed, it returns to the remanent flux state that represents a binary zero.

To write a binary one into a cell that has been read, the positive field created by the positive current pulse is applied to the cell, reversing its magnetization. Positive current pulses in coincidence in the X and Y wires produce this field. To

write a zero, however, really means to leave a cell essentially in the state resulting from the read operation. Therefore, the positive field applied to the cell must be weaker than the coercive force of the ferrite material. To achieve this, a negative current pulse is applied to the inhibit winding to create a negative field that opposes or cancels a part of the positive write field. Thus, the net field is not great enough to switch a large amount of flux in the cell. Following the write pulses, a negative pulse, called a post-write disturb pulse, is applied to the inhibit winding. This stabilizes the magnetization of the cell and improves its operating margins.

We have described the reading and writing operations on a single cell. To form the 24-bit word of the ferrite sheet, parallel operations are performed on 24 cells. Each cell, or bit, in a word is linked by common X and Y windings. Each inhibit and each sense winding links the bits in the same positions in each word of the module. In this way, a combination of one X, one Y, and one inhibit winding uniquely defines one bit in the memory.

A single module is wired with 64 Y conductors, 32 X conductors, and 24 interlaced inhibit and sense windings. Each path connects the cells it passes through in series electrically. Physically, each of these windings lies completely within a separate plane. Three planes containing one X, one Y, and one sense and inhibit winding are mutually orthogonal and their intersection defines a single bit or memory cell. The coincidence of an X and a Y winding plane, therefore, defines an entire word of 24 bits. A Y conductor, electroplated on each ferrite sheet during manufacture, links all the cells in that sheet in series. Each Y conductor in the module is formed by serially connecting the conductors of the three sheets in corresponding levels of the three stacks. The X conductor is a single wire threaded up and down through the cells in a stack. Inhibit and series windings are threaded through the cells in a similar fashion. The drawing on page 231 shows the wiring patterns in a cutaway section of the module.

Although coincident currents are required to switch a cell, a single pulse on either the X or Y conductor "half-selects" a bit and causes a small reversible change from the remanent flux of the magnetic material. This change generates a small voltage that interferes with the signal at the output of the conductor. In a large memory, the outputs of all half-selected bits linked by a common path add coherently and the sum of their amplitudes could exceed the wanted sig-

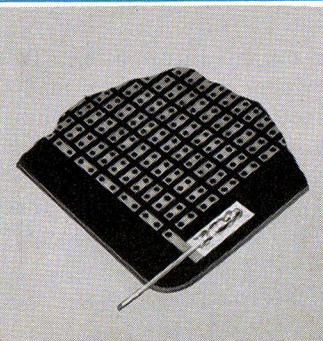
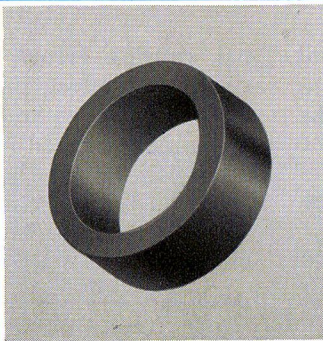
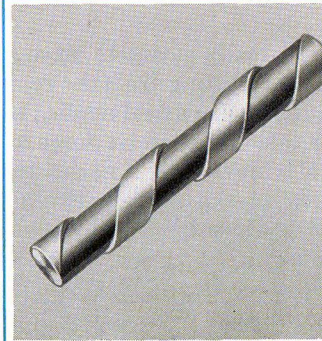
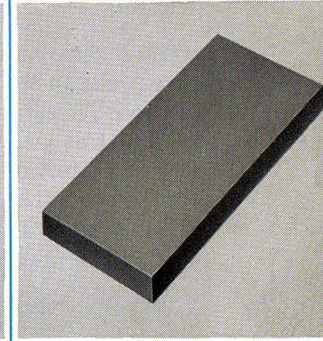
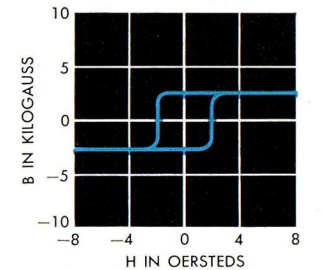
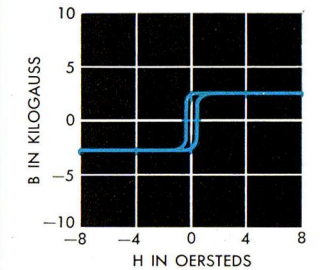
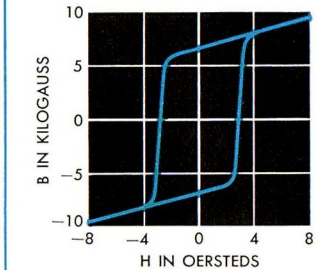
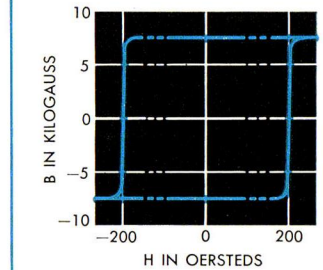
nal, causing errors in output information. To reduce this effect, the wiring patterns in a module are designed to cancel most of the outputs of the half-selected bits. Complete cancellation is not possible since the amplitude of this noise depends on the sense of information stored in the half-selected bits. Thus, noise due to half-selected bits is a factor limiting the size of the memory.

The Twistor Memory

Now let us turn to the twistor memory. Its basic module is an accordion-folded stack of 64 flat planes, each having an array of 2816 twistor cells on each side. Into this stack are inserted 128 memory cards, one card facing each side of each plane. The cards, made of aluminum, bear a matching array of 2816 tiny permanent magnets (see the photograph on page 206) arranged in a grid of 44 rows and 64 columns. One program store (see page 221) contains 16 of these modules with a total storage capacity of 5.8 million bits of information. The store is organized into 131,072 words of 44 bits each. In contrast to the ferrite sheet memory, the twistor can be read an unlimited number of times without destroying the stored information. However, this does incur a penalty. Stored information cannot be changed electrically within the module. It is changed by temporarily removing the twistor cards and magnetizing or demagnetizing the permanent magnets.

These magnets, which are rectangles of vic-alloy, are the basic memory cells. A magnetized spot represents a binary zero; a spot that is unmagnetized represents a one. Twistor wire—a copper wire that has been helically wrapped with a thin permalloy tape—runs along the twistor plane under each row of magnets. A copper strap runs under each column, intersecting orthogonally with a twistor wire directly under each magnet. The intersection of a copper strap and a twistor wire forms a twistor cell which senses the condition of the memory cell or magnet. Twistor wires are formed into two flat cables that link all planes in a stack. Each twistor wire (there are 44 in a cable) reads out one bit in a word. A copper wire, parallel to each twistor wire, completes the transmission path for output signals. Each copper strap (there are 64 to a plane) defines the bits in a complete memory word.

The manner in which the twistor cell senses the state of the vic-alloy magnet can be described quite simply. (See the drawing on page 232.) Magnetic flux in the permalloy tape wraps helically around the twistor wire and links both the wire and the copper strap at every intersection. Because this flux path closes through the air, the twistor cell is

MATERIAL:	FERRITE	FERRITE	PERMALLOY	VICALLOY
COMPOSITION:	Fe, Mg, Mn	Fe, Cd, Mg, Mn	Ni, Mo, Fe	Va, Fe, Co
USE:				
STATIC HYSTERESIS LOOP:				
B _r :	2000 GAUSS	2000 GAUSS	7000 GAUSS	8000 GAUSS
H _c :	2 OERSTEDS	0.2 OERSTEDS	3 OERSTEDS	200 OERSTEDS
SQUARENESS:	0.97	0.95	0.7	

Characteristics of magnetic materials in the ferrite sheet and the permanent magnet twistor memories. Left to right: ferrite sheet, twistor ferrite core switch, twistor wire, and twistor card vicalloy magnet.

sensitive to ambient magnetic fields. Thus the strong field of the vicalloy magnet can affect the operation of the twistor cell. If the spot over an intersection is not magnetized, the field due to a current pulse in the strap will reverse the magnetization, i.e. switch the twistor cell. This induces a voltage pulse in the twistor wire which is read as a binary one. On the other hand, if the spot is magnetized, its external field saturates the permalloy tape at the intersection. Then the pulse in the copper strap cannot reverse the magnetization of the twistor cell. Therefore, only a small change of flux takes place, inducing only a small voltage in the twistor wire. This voltage is read as a binary zero.

Random access to any word in the twistor memory is provided by connecting each copper strap to a ferrite core in a matrix of biased core switches. These switches operate much like the cores of a coincident core memory except that their threshold field (the field necessary to make them change state), is generated by a current in a bias winding, not by the coercive force of the magnetic material. Two sets of access windings—one running parallel to the planes, the other per-

pendicular to them—connect the switches to the memory input terminals. The core selected by the two energized windings acts as a current transformer and generates the current pulse in the copper strap.

Uniform behavior of magnetic memory cells depends primarily upon uniformity of the magnetic properties of the materials from which they are made. In both the ferrite sheet and twistor memories, these materials have been developed to have the characteristics necessary for memory operation (see the table on this page.) The story of the development of the twistor material is told later in this issue. (See *Some Magnetic Materials*.)

We have discussed only the basic operation of the permanent magnet twistor memory. Several features of the design are important to No. 1 ESS. The magnet card material is aluminum. Because of its high conductivity, the card serves as an integral electrical part of the memory, as well as a mechanical means of placing the magnets properly. Eddy currents flowing in the card that arise from currents in the copper straps produce additional magnetic fields that add to

and enhance the original fields. This makes the copper word strap more efficient and reduces its impedance.

Because it is grounded through the retaining spring structure and the frame of the module, the card also serves as a conducting ground plane which reduces common-mode noise in the twistor line. A permalloy sheet, placed under the copper straps, also contributes to the effectiveness of the strap currents. The permalloy concentrates the magnetic field of the strap current in the vicinity of the twistor cell. It serves also as a distributed magnetic shield that reduces the effect of unwanted ambient magnetic fields.

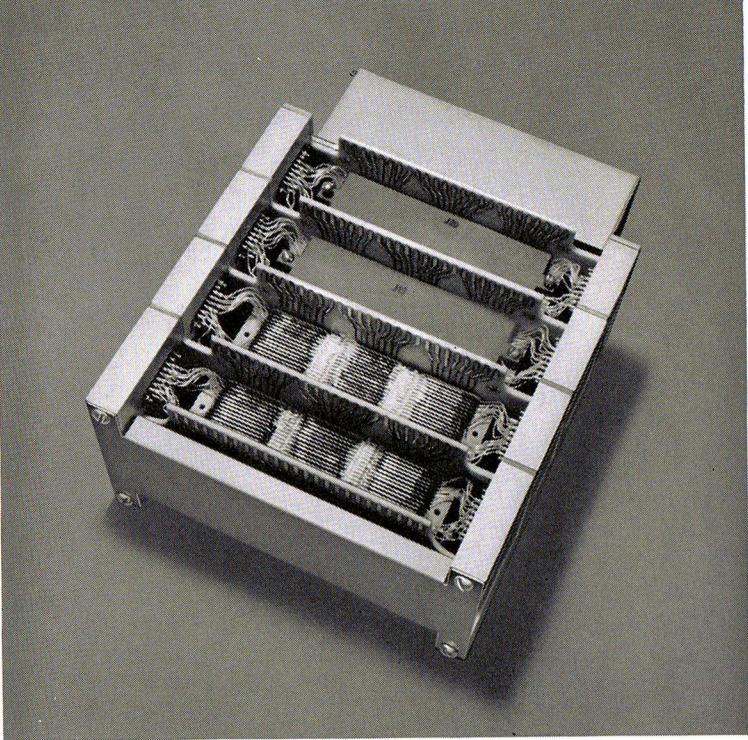
Reading and writing in the memories, then, can be described in terms of a single bit and the operations on a memory word are parallel interactions of the basic action. But the construction of the No. 1 ESS memories must be considered in terms of blocks of cells.

Among the primary design goals of both memories were low first cost and low maintenance cost. It would be prohibitively expensive to fabricate individual cells and then interconnect them. The solution to the problem of low first cost is to fabricate a large number of cells and their interconnections in a few common steps. Low maintenance cost depends upon building a device with long life and stable characteristics so that adjustment during service is unnecessary.

Memory cells must be exceptionally uniform, because if a single cell fails an entire module is rejected. Materials and processes were developed to promote uniformity. The memory structures were designed to support the cells so that changing ambient conditions affect them as little as possible. In common with older magnetic components, such as transformers, the No. 1 ESS memories should not show any appreciable aging due to changes in their primary magnetic characteristics.

In the ferrite sheet memory, the 256 cells of each single sheet are formed simultaneously. Ferrite powder is pressed into the sheet which is first fired and then metallized. During the last step, the Y conductor is plated directly on the sheet. The frame of the module is designed to hold all the sheets in alignment and support them without strain. This meets the mechanical objective and it also facilitates wiring. As a result of this method of manufacture, the ferrite sheet memory, in comparison to earlier core memories, requires fewer interconnections. The result of this is significant improvement in first cost and reliability.

In the twistor memory, the objectives of a



One module of the ferrite sheet memory. An office of about 10,000 lines generally requires two or more call stores (8 modules). A 65,000 line office with a high calling rate may contain 40 stores.

minimum number of connections and the elimination of mechanical strain on the magnetic elements are achieved in one operation. The twistor wire cable, running continuously through a module, is laminated between sheets of polyester which hold the wires in precise position and protect them as well.

The memories for No. 1 ESS have been designed specifically for their application in a digital control system which must operate continuously in real time. The permanent magnet twistor provides a semipermanent memory device uniquely suited to the storage of program and translation data in this system. General purpose digital computers use no directly comparable memory device. The ferrite sheet memory, while its electrical properties are directly comparable to the core memories in general use, is an exceptionally compact memory containing about 350 bits per cubic inch. Excluding terminals and connectors, the density is 8000 bits per cubic inch. For comparison, the twistor memory contains about 250 bits per cubic inch.

In the last three years, the Western Electric Company has manufactured many twistor memory modules and ferrite sheet memory modules. Test experience has amply demonstrated the uniformity of the electrical performance in these memories and the efficiency of producing arrays of memory elements in common operations on a large scale.